



PARA LIGHT ELECTRONICS CO., LTD.

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DATA SHEET

PART NO. : L-314LPG6D

REV : A / 0

CUSTOMER'S APPROVAL : _____

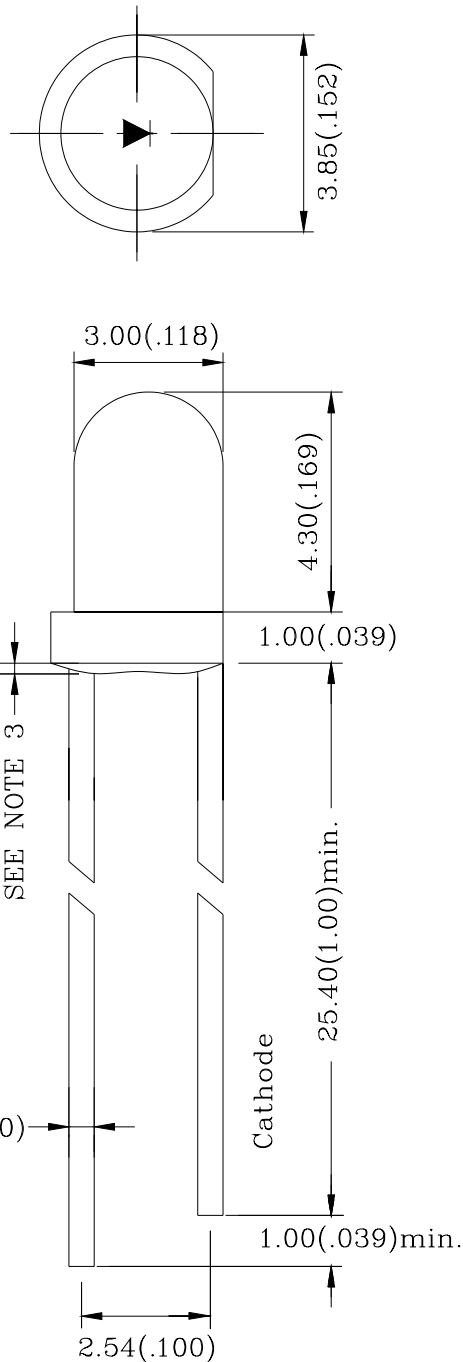
DCC : _____

DRAWING NO. : DS-33-03-0410

DATE : 2003-08-07

Page : 1

PACKAGE DIMENSIONS



Note:

- 1.All Dimensions are in millimeters.
- 2.Tolerance is $\pm 0.25\text{mm}$ (0.010 ") Unless otherwise specified.
- 3.Protruded resin under flange is 1.5mm(0.059 ") max.
- 4.Lead spacing is measured where the leads emerge from the package.
- 5.Specification are subject to change without notice
- 6.highlight $< -400\text{V}$ the led can withstand the max static level when assembling or operation.

FEATURES

- * SUITABLE HIGH PULSE CURRENT OPERATION
- * EXTRA HIGH RADIANT POWER AND RADIANT INTENSITY
- * HIGH RELIABILITY
- * LOW FORWARD VOLTAGE

CHIP MATERIALS

- * Dice Material : GaInN/GaN
- * Light Color : ULTRA PURE GREEN
- * Lens Color : GREEN DIFFUSED

ABSOLUTE MAXIMUM RATING:(Ta=25°C)

SYMBOL	DESCRIPTION	ULTRA PURE GREEN	UNIT
PAD	Power Dissipation Per Chip	120	mW
VR	Reverse Voltage Per Chip	5	V
IF	Average Forward Current Per Chip	30	mA
-	Derating Linear From 25°C Per Chip	0.4	mA/°C
Topr	Operating Temperature Range	-25°C to 85°C	
Tstg	Storage Temperature Range	-40°C to 85°C	
Lead Soldering Temperature { 1.6mm(0.063 inch) From Body } 260°C±5°C For 5 Seconds			

ELECTRO-OPTICAL CHARACTERISTICS:(Ta=25°C)

SYMBOL	DESCRIPTION	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
VF	Forward Voltage	IF = 20mA		3.7	4.0	V
IR	Reverse Current	VR = 5V			100	μA
λD	Dominant Wavelength	IF = 20mA		528		nm
Δλ	Spectral Line Half-Width	IF = 20mA		22		nm
2θ1/2	Half Intensity Angle	IF = 20mA		60		deg
Iv	Luminous Intensity	IF = 20mA		500	-	mcd

